## KBJ4005 THRU KBJ410-HAF

## Glass Passivated Single-Phase Bridge Rectifier

Reverse Voltage - 50 to 1000 V

## Forward Current - 4A

## KBJ

## Features

- Glass passivated chip junction
- Low forward voltage drop
- Low reverse leakage current
- High surge current capability
- Halogen and Antimony Free(HAF), RoHS compliant


## Mechanical Data

- Case: Molded plastic, KBJ
- Mounting Position: Any


Dimensions in inches and (millimeters)

## Maximum Ratings and Electrical Characteristics

Ratings at $25^{\circ} \mathrm{C}$ ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz , resistive or inductive load.
For capacitive load, derate by 20\%.

| Parameter | Symbols | KBJ4005 | KBJ401 | KBJ402 | KBJ404 | KBJ406 | KBJ408 | KBJ410 | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Maximum Repetitive Peak Reverse Voltage | $\mathrm{V}_{\text {RRM }}$ | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum RMS Voltage | $\mathrm{V}_{\text {RMS }}$ | 35 | 70 | 140 | 280 | 420 | 560 | 700 | V |
| Maximum DC Blocking Voltage | $V_{D C}$ | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Average Rectified Rectified Current at $\mathrm{T}_{\mathrm{C}}=115^{\circ} \mathrm{C}$ | $\mathrm{I}_{\text {(AV) }}$ | 4 |  |  |  |  |  |  | A |
| Non-repetitive Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method) | $\mathrm{I}_{\text {FSM }}$ | 120 |  |  |  |  |  |  | A |
| Maximum Forward Voltage at 2 A | $V_{\text {F }}$ | 1 |  |  |  |  |  |  | V |
| Maximum Reverse Current $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ <br> at Rated DC Blocking Voltage $\mathrm{T}_{\mathrm{A}}=125^{\circ} \mathrm{C}$ | $\mathrm{I}_{\mathrm{R}}$ | $\begin{gathered} 5 \\ 500 \end{gathered}$ |  |  |  |  |  |  | $\mu \mathrm{A}$ |
| Typical Junction Capacitance ${ }^{1)}$ | $\mathrm{C}_{\mathrm{j}}$ | 40 |  |  |  |  |  |  | pF |
| Typical Thermal Resistance ${ }^{2)}$ | $\mathrm{R}_{\text {өJc }}$ | 5.5 |  |  |  |  |  |  | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Operating Junction Temperature Range | $\mathrm{T}_{\mathrm{j}}$ | -55 to +150 |  |  |  |  |  |  | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $\mathrm{T}_{\text {stg }}$ | -55 to + 150 |  |  |  |  |  |  | ${ }^{\circ} \mathrm{C}$ |

[^0]

FIG.3- TYPICAL INSTANTANEOUS FORWARD


FIG.2- MAXIMUM FORWARD CURRENT DERATING CURVE PER BRIDGE ELEMENT


FIG.4- TYPICAL REVERSE CHARACTERISTICS



[^0]:    ${ }^{1)}$ Measured at 1 MHz and applied reverse voltage of 4 V DC
    ${ }^{2)}$ Thermal Resistance from Junction to Case with Device Mounted on $75 \mathrm{~mm} \times 75 \mathrm{~mm} \times 1.6 \mathrm{mmCu}$ Plate Heatsink.

